



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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TECHNOLOGY CENTER 2830

Applicant: Jian-Shen Yu

) Group Art No.: 2826

Application No: 10/071,063

) Examiner: Mandala, Victor A.

Filed: February 7, 2002

) Re: RESPONSE

For: "THIN-FILM TRANSISTOR  
ARRAY STRUCTURE"

) Our Ref: B-4494 619514-6/RPB

) Date: November 13, 2002

#5/a<sub>3</sub>

12-23-02

agf

Honorable Commissioner of Patents and Trademarks  
Washington, D.C. 20231

Dear Sir:

This paper is filed in response to the Official Action dated August 14, 2002. Please enter the following amendments and remarks into the prosecution history of the subject application without prejudice. Enclosed herewith are an excess claims paper and a letter to the Patent Office's draftsman.

11/20/2002 DTESSEM1 00000130 10071063

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IN THE SPECIFICATION

1.

Please amend the term "drain electrode 12" of page 1 (see also first line of page 2), lines 30-31 of the application as filed to "source electrode 12." The last paragraph of page 1 of the specification will now read as follows:

a  
"Referring to Fig. 1A, Fig. 1A is a plan view showing the structure of one pixel of typical TFT structure. Symbol "CE" represents a common electrode, symbol "SL" represents a scanning line, symbol "10" represents a TFT, and symbol "DL" represents a data line. The source electrode 12 of the TFT 10 is coupled to an ITO electrode (i.e. pixel electrode) 16 via a contact hole 14 formed on an isolated layer, and the data line DL is coupled to a